# Single low-ohmic 8-channel analog switch Rev. 1 — 7 August 2012

Product data sheet

#### **General description** 1.

The NX3L4051-Q100 is a low-ohmic 8-channel analog switch, suitable for use as an analog or digital multiplexer/demultiplexer. The NX3L4051-Q100 has three digital select inputs (S1 to S3), eight independent inputs/outputs (Y0 to Y7) and a common input/output (Z). All eight switches share an enable input (E). A HIGH on E causes all switches into the high impedance OFF-state, independent of Sn.

Schmitt trigger action at the digital inputs makes the circuit tolerant to slower input rise and fall times. Low threshold digital inputs allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I<sub>CC</sub>. This makes it possible for the NX3L4051-Q100 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The NX3L4051-Q100 allows signals with amplitude up to  $V_{CC}$  to be transmitted from Z to Yn or from Yn to Z. The low ON resistance (0.5  $\Omega$ ) and flatness (0.13  $\Omega$ ), ensures minimal attenuation and distortion of transmitted signals.

This product has been gualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### Features and benefits 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
  - 1.7 Ω (typical) at V<sub>CC</sub> = 1.4 V
  - 1.0 Ω (typical) at V<sub>CC</sub> = 1.65 V
  - 0.6 Ω (typical) at V<sub>CC</sub> = 2.3 V
  - 0.5 Ω (typical) at V<sub>CC</sub> = 2.7 V
  - 0.5 Ω (typical) at V<sub>CC</sub> = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
  - MIL-STD-883, method 3015 Class 3A exceeds 7500 V
  - HBM JESD22-A114F Class 3A exceeds 7500 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
  - CDM AEC-Q100-011 revision B exceeds 1000 V
  - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption



#### Single low-ohmic 8-channel analog switch

- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at V<sub>CC</sub> = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V<sub>CC</sub>
- High current handling capability (350 mA continuous current under 3.3 V supply)

### 3. Applications

- Cell phone
- PDA
- Portable media player
- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

### 4. Ordering information

### Table 1.Ordering information

Type number	Package	ackage									
	Temperature range	Name	Description	Version							
NX3L4051HR-Q100	–40 °C to +125 °C	HXQFN16	plastic thermal enhanced extremely thin quad flat package; no leads; 16 terminals; body $3 \times 3 \times 0.5$ mm	SOT1039-2							
NX3L4051PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1							

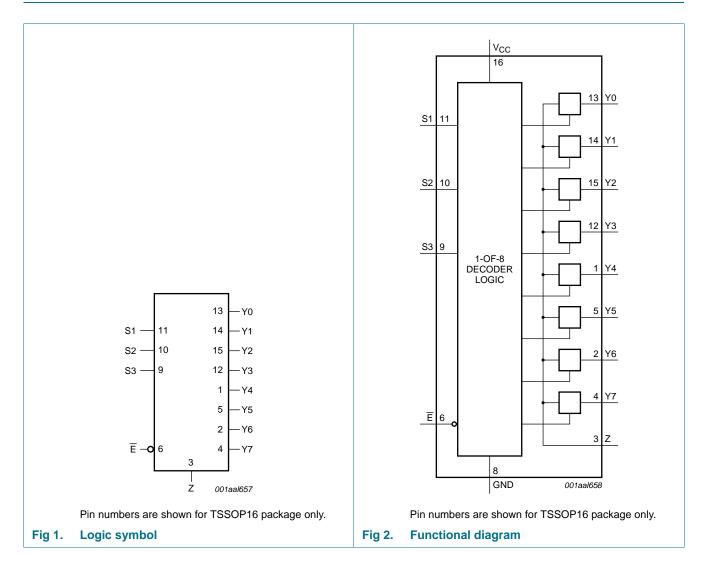
### 5. Marking

#### Table 2.Marking codes

Type number	Marking code
NX3L4051HR-Q100	M41
NX3L4051PW-Q100	X3L4051

Single low-ohmic 8-channel analog switch

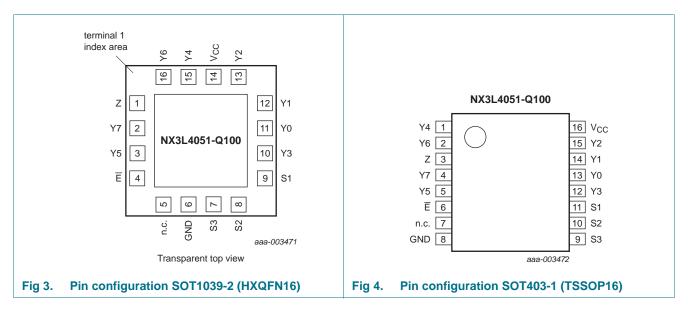
### 6. Functional diagram



Single low-ohmic 8-channel analog switch

### 7. Pinning information

### 7.1 Pinning



### 7.2 Pin description

#### Table 3. Pin description

Symbol	Pin	Description	
	SOT1039-2	SOT403-1	_
Y0, Y1, Y2, Y3, Y4, Y5, Y6, Y7	11, 12, 13, 10, 15, 3, 16, 2	13, 14, 15, 12, 1, 5, 2, 4	independent input or output
Z	1	3	independent output or input
Ē	4	6	enable input (active LOW)
n.c.	5	7	not connected
GND	6	8	ground (0 V)
S1, S2, S3	9, 8, 7	11, 10, 9	select input
V <sub>CC</sub>	14	16	supply voltage

Single low-ohmic 8-channel analog switch

### 8. Functional description

Table 4.	Function table <sup>[1]</sup>			
Input		Channel ON		
E	S3	S2	S1	
L	L	L	L	Y0 = Z
L	L	L	Н	Y1 = Z
L	L	Н	L	Y2 = Z
L	L	Н	Н	Y3 = Z
L	Н	L	L	Y4 = Z
L	Н	L	Н	Y5 = Z
L	Н	Н	L	Y6 = Z
L	Н	Н	Н	Y7 = Z
Н	Х	Х	Х	switches off

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

### 9. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

				10	'
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
VI	input voltage	Sn and $\overline{E}$	<u>[1]</u> –0.5	+4.6	V
V <sub>SW</sub>	switch voltage		2 -0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 V$	-50	-	mA
I <sub>SK</sub>	switch clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±50	mA
I <sub>SW</sub>	switch current	$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; source or sink current	-	±350	mA
		$V_{SW}$ > -0.5 V or $V_{SW}$ < $V_{CC}$ + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$			
		HXQFN16	<u>[3]</u>	250	mW
		TSSOP16	<u>[4]</u>	500	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For HXQFN16 package: above 135 °C the value of P<sub>tot</sub> derates linearly with 16.9 mW/K.

[4] For TSSOP16 package: above 60 °C the value of P<sub>tot</sub> derates linearly with 5.5 mW/K.

Single low-ohmic 8-channel analog switch

### **10.** Recommended operating conditions

Table 6.	Recommended operating conditions							
Symbol	Parameter	Conditions	Min	Max	Unit			
V <sub>CC</sub>	supply voltage		1.4	4.3	V			
VI	input voltage	Sn and E	0	4.3	V			
V <sub>SW</sub>	switch voltage		<u>[1]</u> 0	V <sub>CC</sub>	V			
T <sub>amb</sub>	ambient temperature		-40	+125	°C			
$\Delta t / \Delta V$	input transition rise and fall rate	Sn and $\overline{E}$ ; V <sub>CC</sub> = 1.4 V to 4.3 V	-	200	ns/V			

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current flows from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

### **11. Static characteristics**

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> =	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
VIH	HIGH-level	$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	0.9	-	-	0.9	-	-	V
	input voltage	$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	0.9	-	-	0.9	-	-	V
		$V_{CC}$ = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	1.3	-	-	1.3	-	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	1.4	-	-	1.4	-	-	V
VIL	IL LOW-level input voltage	$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	-	0.3	-	0.3	0.3	V
		$V_{CC}$ = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		$V_{CC}$ = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V
	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.5	-	0.5	0.5	V	
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	0.6	-	0.6	0.6	V
I	input leakage current	Sn and $\overline{E}$ ; V <sub>I</sub> = GND to 4.3 V; V <sub>CC</sub> = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I <sub>S(OFF)</sub>	OFF-state	Yn ports; see <u>Figure 5</u>							
	leakage current	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I <sub>S(ON)</sub>	ON-state leakage current	Z port; V <sub>CC</sub> = 1.4 V to 3.6 V; see <u>Figure 6</u>							
		$V_{CC}$ = 1.4 V to 3.6 V	-	-	±20	-	±200	±2000	nA
		$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±40	-	±200	±2000	nA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or $V_{CC}$							
		$V_{CC} = 3.6 V$	-	-	100	-	500	5000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	6000	nA
NX3L4051_Q100		All information provided in this d	ocument is subje	ct to legal discla	aimers.		© NXP	B.V. 2012. All righ	its reserve

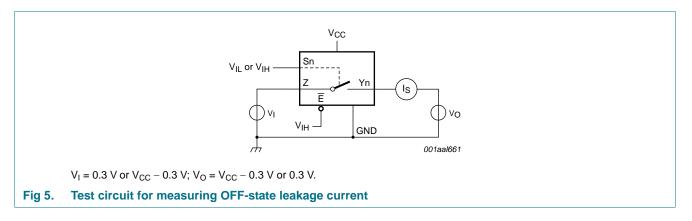
#### Single low-ohmic 8-channel analog switch

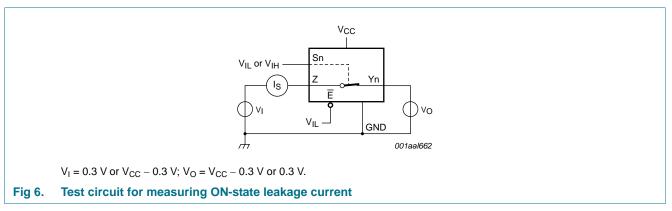
Symbol	Parameter	Conditions	T,	amb = 25	°C	T <sub>amb</sub> =	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	_
$\Delta I_{CC}$	additional	$V_{SW} = GND \text{ or } V_{CC}$					1		
	supply current	$V_1 = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μA
		$V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μΑ
		$V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	7.0	10.0	-	15	15	μΑ
		$V_{I} = 1.8 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	2.5	4.0	-	5	5	μΑ
		$V_{I} = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$	-	50	200	-	300	500	nA
CI	input capacitance	Sn and $\overline{E}$	-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
$C_{S(ON)}$	ON-state capacitance		-	350	-	-	-	-	pF

#### Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

### 11.1 Test circuits





NX3L4051\_Q100

Single low-ohmic 8-channel analog switch

### 11.2 ON resistance

#### Table 8. ON resistance<sup>[1]</sup>

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 14.

Symbol	Parameter	Conditions	T <sub>amb</sub> =	-40 °C to	o +85 °C	$T_{amb} = -40$ °	C to +125 °C	Unit
			Min	Typ[2]	Max	Min	Max	
R <sub>ON(peak)</sub>	ON resistance (peak)	$V_I = GND$ to $V_{CC}$ ; $I_{SW} = 100$ mA; see <u>Figure 7</u>						
		$V_{CC} = 1.4 V$	-	1.7	3.7	-	4.1	Ω
		V <sub>CC</sub> = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.6	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
$\Delta R_{ON}$	ON resistance mismatch	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	3 <u>]</u>					
	between channels	$V_{CC}$ = 1.4 V; $V_{SW}$ = 0.4 V	-	0.18	0.30	-	0.30	Ω
	Channels	$V_{CC}$ = 1.65 V; $V_{SW}$ = 0.5 V	-	0.18	0.20	-	0.30	Ω
		$V_{CC}$ = 2.3 V; $V_{SW}$ = 0.7 V	-	0.07	0.10	-	0.13	Ω
		$V_{CC}$ = 2.7 V; $V_{SW}$ = 0.8 V	-	0.07	0.10	-	0.13	Ω
		$V_{CC}$ = 4.3 V; $V_{SW}$ = 0.8 V	-	0.07	0.10	-	0.13	Ω
R <sub>ON(flat)</sub>	ON resistance (flatness)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	<u>4]</u>					
		$V_{CC} = 1.4 V$	-	1.0	3.3	-	3.6	Ω
		V <sub>CC</sub> = 1.65 V	-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 V$	-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 V$	-	0.13	0.3	-	0.35	Ω
		$V_{CC} = 4.3 V$	-	0.2	0.4	-	0.45	Ω

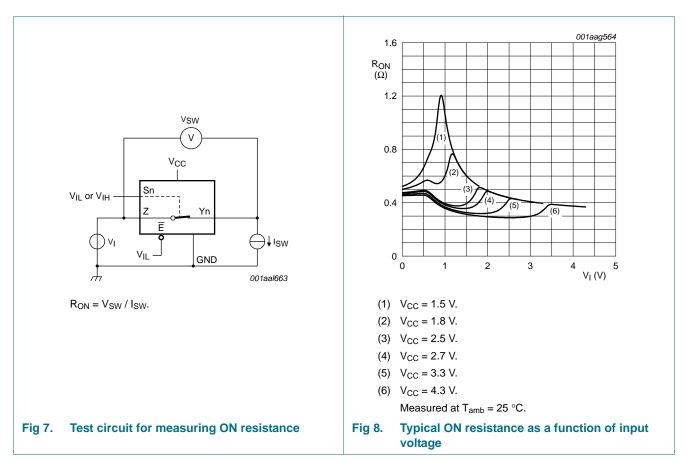
[1] For NX3L4051PW-Q100 (TSSOP16 package), all ON resistance values are up to 0.05  $\Omega$  higher.

[2] Typical values are measured at  $T_{amb} = 25 \ ^{\circ}C$ .

[3] Measured at identical V<sub>CC</sub>, temperature and input voltage.

[4] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V<sub>CC</sub> and temperature.

Single low-ohmic 8-channel analog switch

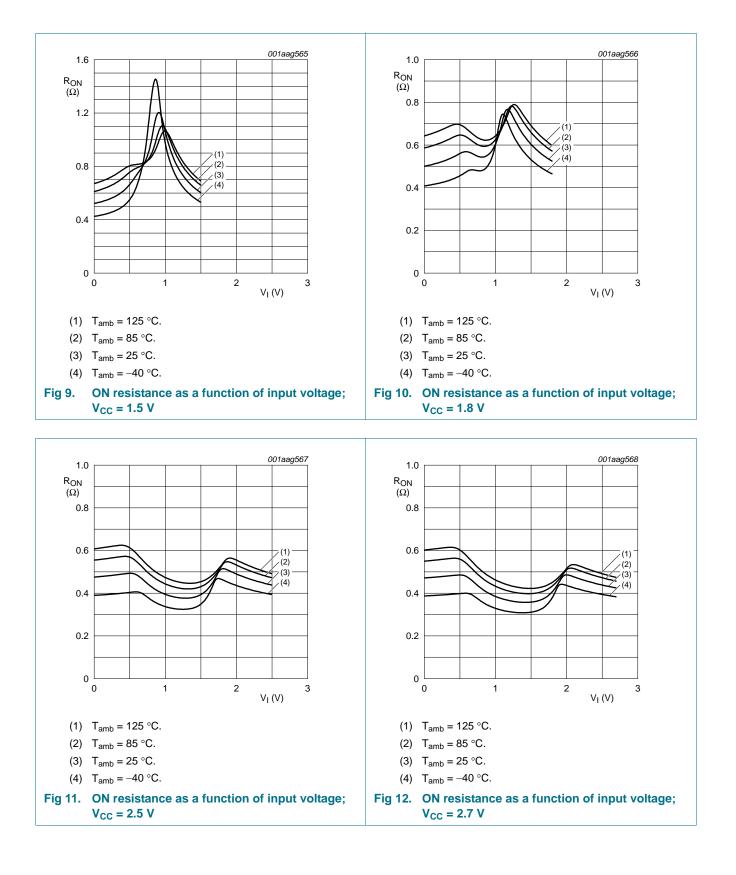


### 11.3 ON resistance test circuit and graphs

NX3L4051\_Q100
Product data sheet

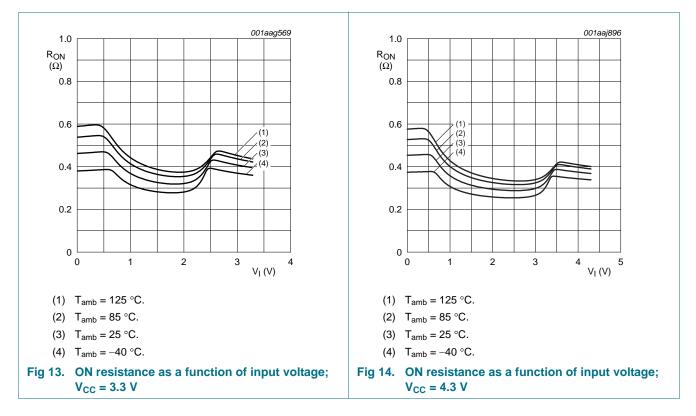
## NX3L4051-Q100

#### Single low-ohmic 8-channel analog switch



## NX3L4051-Q100

#### Single low-ohmic 8-channel analog switch



### 12. Dynamic characteristics

#### Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Parameter	Conditions	Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> =	–40 °C to	+125 °C	Unit
			Min	Тур <u><sup>[1]</sup></u>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>en</sub>	enable time	Ē, Sn to Z or Yn; see <u>Figure 15</u>							
		$V_{CC}$ = 1.4 V to 1.6 V	-	45	100	-	120	125	ns
		$V_{CC}$ = 1.65 V to 1.95 V	-	32	75	-	85	95	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	21	50	-	55	60	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	19	45	-	45	50	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	19	45	-	45	50	ns
t <sub>dis</sub>	disable time	Ē, Sn to Z or Yn; see <u>Figure 15</u>							
		$V_{CC}$ = 1.4 V to 1.6 V	-	25	80	-	90	105	ns
		$V_{CC}$ = 1.65 V to 1.95 V	-	15	65	-	70	75	ns
		$V_{CC}$ = 2.3 V to 2.7 V	-	9	30	-	35	40	ns
		$V_{CC}$ = 2.7 V to 3.6 V	-	8	25	-	30	35	ns
		$V_{CC}$ = 3.6 V to 4.3 V	-	8	25	-	30	35	ns

Single low-ohmic 8-channel analog switch

Symbol	Parameter	Conditions		Ta	<sub>mb</sub> = 25	°C	T <sub>amb</sub> =	–40 °C to	+125 °C	Unit
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	
t <sub>b-m</sub>	break-before-make	see Figure 16	[2]							
	time	$V_{CC}$ = 1.4 V to 1.6 V		-	19	-	9	-	-	ns
		$V_{CC}$ = 1.65 V to 1.95 V		-	17	-	7	-	-	ns
		$V_{CC}$ = 2.3 V to 2.7 V		-	12	-	4	-	-	ns
		$V_{CC}$ = 2.7 V to 3.6 V		-	10	-	3	-	-	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		-	9	-	2	-	-	ns

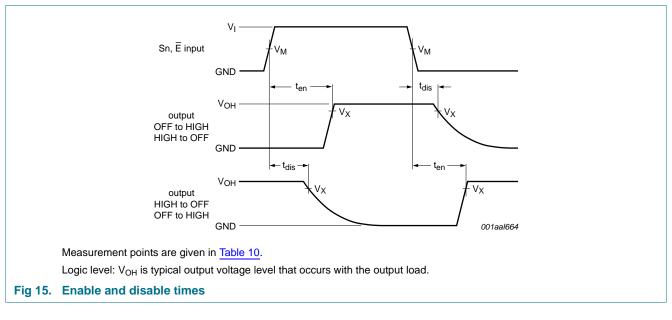
#### Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17

[1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

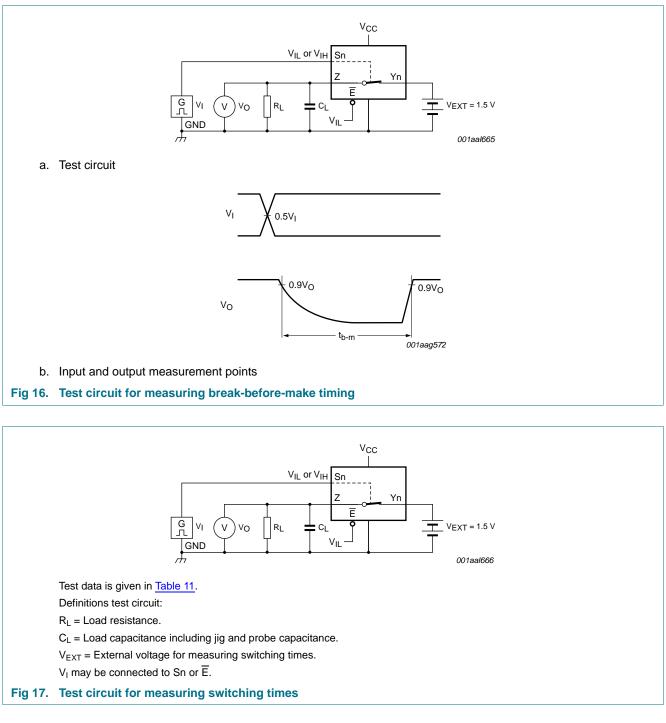
### 12.1 Waveform and test circuits



#### Table 10. Measurement points

Supply voltage	Input	Output
V <sub>cc</sub>	V <sub>M</sub>	V <sub>X</sub>
1.4 V to 4.3 V	0.5V <sub>CC</sub>	0.9V <sub>OH</sub>

### Single low-ohmic 8-channel analog switch



#### Table 11. Test data

Supply voltage	Input		Load	
V <sub>cc</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>
1.4 V to 4.3 V	V <sub>CC</sub>	≤ 2.5 ns	35 pF	50 Ω

Single low-ohmic 8-channel analog switch

### 12.2 Additional dynamic characteristics

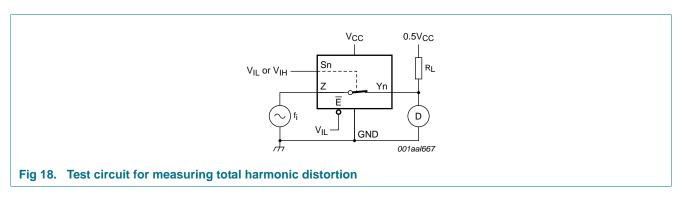
#### Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $V_I = GND$  or  $V_{CC}$  (unless otherwise specified);  $t_r = t_f \le 2.5$  ns;  $T_{amb} = 25$  °C.

Symbol	Parameter	Conditions	Mi	n Typ	Max	Unit
THD	total harmonic distortion	$f_i = 20 \text{ Hz to } 20 \text{ kHz}; \text{ R}_L = 32 \Omega; \text{ see } \frac{\text{Figure } 18}{1000 \text{ sec}}$	<u>[1]</u>			
		V <sub>CC</sub> = 1.4 V; V <sub>I</sub> = 1 V (p-p)		- 0.15	-	%
		V <sub>CC</sub> = 1.65 V; V <sub>I</sub> = 1.2 V (p-p)		- 0.10	-	%
		V <sub>CC</sub> = 2.3 V; V <sub>I</sub> = 1.5 V (p-p)		- 0.02	-	%
		V <sub>CC</sub> = 2.7 V; V <sub>I</sub> = 2 V (p-p)		- 0.02	-	%
		V <sub>CC</sub> = 4.3 V; V <sub>I</sub> = 2 V (p-p)		- 0.02	-	%
f <sub>(-3dB)</sub>	-3 dB frequency	$R_L = 50 \Omega$ ; see Figure 19	[1]			
. ,	response	$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$		- 15	-	MHz
$\alpha_{\text{iso}}$	isolation (OFF-state)	$f_i = 100 \text{ kHz}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 20}}{100 \text{ kHz}}$	[1]			
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$		- –90	-	dB
V <sub>ct</sub>	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$ ; $C_L = 50 \text{ pF}$ ; $R_L = 50 \Omega$ ; see Figure 21				
		V <sub>CC</sub> = 1.4 V to 3.6 V		- 0.2	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		- 0.3	-	V
Xtalk	crosstalk	between switches; $f_i = 100 \text{ kHz}$ ; $R_L = 50 \Omega$ ; see Figure 22	<u>[1]</u>			
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$		- –90	-	dB
Q <sub>inj</sub>	charge injection	$f_i$ = 1 MHz; C <sub>L</sub> = 0.1 nF; R <sub>L</sub> = 1 MΩ; V <sub>gen</sub> = 0 V; R <sub>gen</sub> = 0 Ω; see <u>Figure 23</u>				
		V <sub>CC</sub> = 1.5 V		- 3	-	рС
		V <sub>CC</sub> = 1.8 V		- 4	-	рС
		$V_{CC} = 2.5 V$		- 6	-	рС
		V <sub>CC</sub> = 3.3 V		- 9	-	рС
		$V_{CC} = 4.3 V$		- 15	-	рС

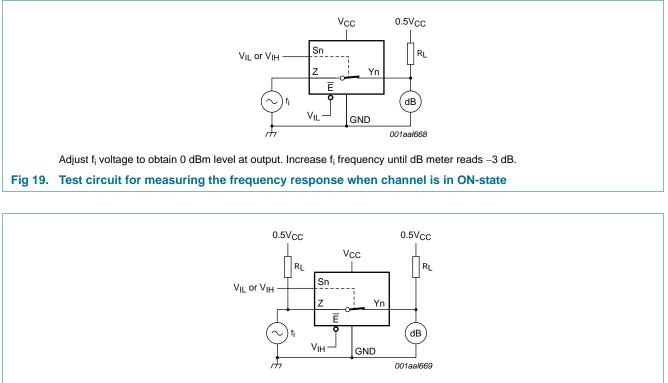
[1]  $f_i$  is biased at 0.5V<sub>CC</sub>.

### 12.3 Test circuits



14 of 23

#### Single low-ohmic 8-channel analog switch



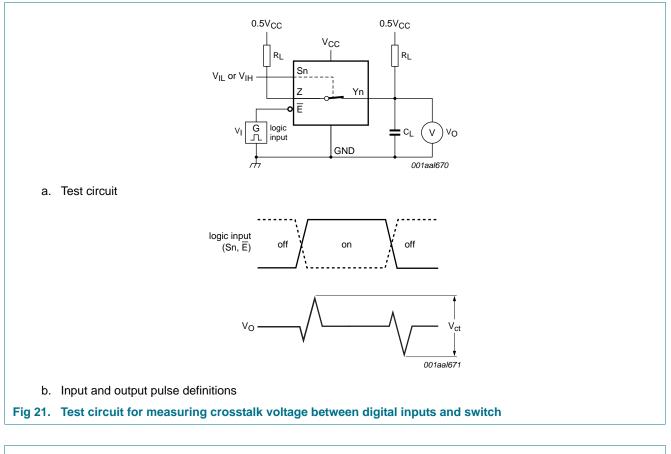
Adjust f<sub>i</sub> voltage to obtain 0 dBm level at input.

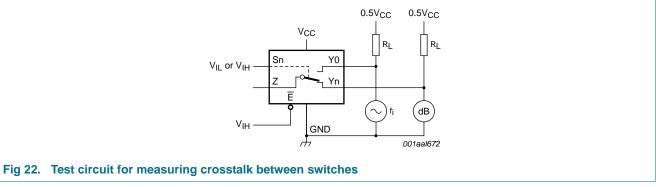
Fig 20. Test circuit for measuring isolation (OFF-state)

NX3L4051\_Q100
Product data sheet

## NX3L4051-Q100

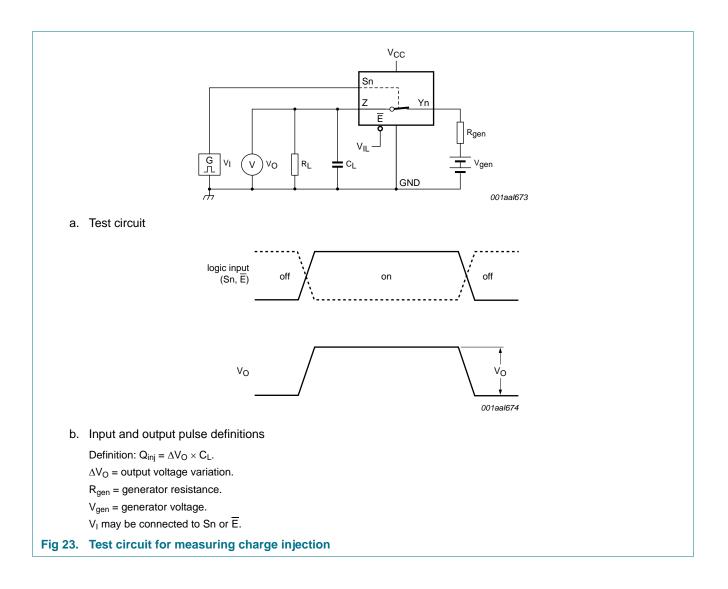
#### Single low-ohmic 8-channel analog switch





## NX3L4051-Q100

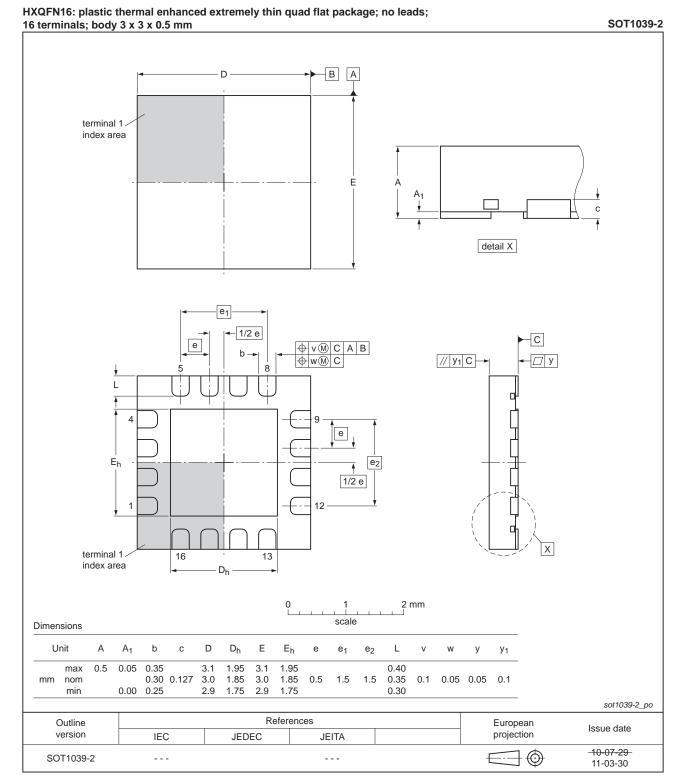
### Single low-ohmic 8-channel analog switch



## NX3L4051-Q100

Single low-ohmic 8-channel analog switch

### 13. Package outline

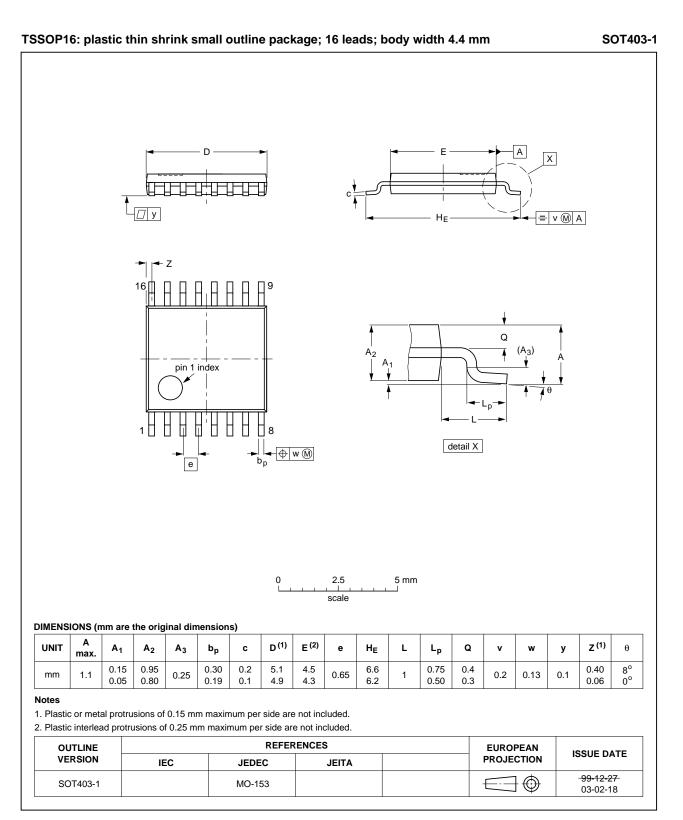


#### Fig 24. Package outline SOT1039-2 (HXQFN16)

All information provided in this document is subject to legal disclaimers.

NX3L4051\_Q100

Single low-ohmic 8-channel analog switch



### Fig 25. Package outline SOT403-1 (TSSOP16)

All information provided in this document is subject to legal disclaimers.

NX3L4051\_Q100

Single low-ohmic 8-channel analog switch

### 14. Abbreviations

Table 13.	Abbreviations			
Acronym	Description			
CDM	Charged Device Model			
CMOS	Complementary Metal-Oxide Semiconductor			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			
PDA	Personal Digital Assistant			
MIL	Military			

### **15. Revision history**

Table 14. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
NX3L4051_Q100 v.1	20120807	Product data sheet	-	-	

Single low-ohmic 8-channel analog switch

### 16. Legal information

### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

### 16.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

#### Suitability for use in automotive applications - This NXP

Semiconductors product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

#### Single low-ohmic 8-channel analog switch

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

### 16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

### **17. Contact information**

For more information, please visit: <a href="http://www.nxp.com">http://www.nxp.com</a>

For sales office addresses, please send an email to: salesaddresses@nxp.com

#### Single low-ohmic 8-channel analog switch

### **18. Contents**

1	General description	1
2	Features and benefits	1
3	Applications	2
4	Ordering information	2
5	Marking	2
6	Functional diagram	3
7	Pinning information	4
7.1		4
7.2	Pin description	4
8	Functional description	5
9	Limiting values	5
10	Recommended operating conditions	6
11	Static characteristics	6
11.1	Test circuits	7
11.2	ON resistance	В
11.3	ON resistance test circuit and graphs	9
12	Dynamic characteristics 1'	1
12.1	Waveform and test circuits 12	2
12.2	Additional dynamic characteristics 14	
12.3	Test circuits 14	1
13	Package outline 18	3
14	Abbreviations 20	D
15	Revision history 20	D
16	Legal information 2 <sup>4</sup>	1
16.1	Data sheet status 2'	1
16.2	Definitions 2	1
16.3	Disclaimers	-
16.4	Trademarks 22	2
17	Contact information 22	2
18	Contents 23	3

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

#### © NXP B.V. 2012.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 7 August 2012 Document identifier: NX3L4051\_Q100

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

NXP: NX3L4051PW,118 NX3L4051HR,115